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# MAILED DEC 1 1 2006 GROUP 2800

## BEFORE THE BOARD OF PATENT APPEALS AND INTERFERENCES

Application Number: 10/608,791

Filing Date: June 26, 2003 Appellent(s): JACKSON ET AL. MAILED
DEC 1 1 2006
GROUP 2800

Robert W. Bergstrom For Appellant

**EXAMINER'S ANSWER** 

This is in response to the appeal brief filed September 1, 2006 appealing from the Office action mailed March 24, 2006.

#### (1) Real Party in Interest

A statement identifying by name the real party in interest is contained in the brief.

#### (2) Related Appeals and Interferences

The examiner is not aware of any related appeals, interferences, or judicial proceedings which will directly affect or be directly affected by or have a bearing on the Board's decision in the pending appeal.

#### (3) Status of Claims

The statement of the status of claims contained in the brief is incorrect. A correct statement of the status of the claims is as follows:

This appeal involves claims 1-32.

The appellant's arguments with respect to Chow (US 6,649,903) are persuasive. The 35 USC 102 Rejection of claims 1-3, 14, 15, and 28-32 over Chow (US 6,649,903) is therefore removed. No other rejection was made for dependent claims 28-31.

Claims 28-31 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Therefore, only claims 1-27 and 32 are finally rejected.

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#### (4) Status of Amendments After Final

The appellant's statement of the status of amendments after final rejection contained in the brief is correct.

#### (5) Summary of Claimed Subject Matter

The summary of claimed subject matter contained in the brief is correct.

#### (6) Grounds of Rejection to be Reviewed on Appeal

The appellant's statement of the grounds of rejection to be reviewed on appeal is substantially correct. The changes are as follows: Claims 1-27 and 32 are the only claims finally rejected. Claims 28-31 are now objected to as depending upon a rejected base claim.

#### WITHDRAWN REJECTIONS

The following grounds of rejection are not presented for review on appeal because the examiner has withdrawn them. The rejection of claims 1-3, 14, 15, and 28-32 over Chow (US 6,649,903).

#### (7) Claims Appendix

The copy of the appealed claims contained in the Appendix to the brief is correct.

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#### (8) Evidence Relied Upon

US Pub. 2003/0230746 A1 Stasiak 12-2003

US Pub. 2004/0246768 A1 Krieger et al. 12-2004

Gold, Victor, "Gold Book, Compendium of Chemical Terminology" First Edition published in 1987, pgs. 1-5. Excerpts were found on Wikipedia website; http://en.wikipedia.org/Chemical\_reaction.

#### (9) Grounds of Rejection

The following ground(s) of rejection are applicable to the appealed claims:

#### Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claim 1 is rejected under 35 U.S.C. 102(e) as being anticipated by Stasiak (US Pub. 2003/0230746 A1).

In re claim 1, Stasiak shows (figs. 1a-1b) an organic polymer based memory element comprising two overlapping conductive signal lines (140 and 130) and at least one organic polymer layer (120) within the region of overlap between the two signal

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lines, the organic polymer layer having at least two detectable memory states [0019], transitions between which arise from one of changes in chemical bonds and changes in organic polymer doping [0023].

Claims 1-27, and 32 are rejected under 35 U.S.C. 102(e) as being anticipated by Krieger et al. (US Pub. 2004/0246768 A1).

In re claim 1, Krieger et al. shows (figs. 1-6) an organic polymer based memory element comprising two overlapping conductive signal lines (upper electrode and lower electrodes 1 and 2) and at least one organic polymer layer (active layer 3) within the region of overlap between the two signal lines [0019], the organic polymer layer having at least two detectable memory states, transitions between which arise from one of changes in chemical bonds and changes in organic polymer doping [0019].

In re claim 2, Krieger discloses [0019] that in the first memory state, the organic polymer exhibits a first electrical resistivity, in the second memory state, the organic polymer exhibits a second electrical resistivity lower than the first, and the element is inherently an antifuse type memory element.

In re claim 3, Krieger discloses [0019] that the memory-state transition is initiated by applying to the memory element state-transition facilitating agents such as electrical voltage.

In re claims 4-13, Krieger shows [figs. 1-5] that the organic polymer layer is adjacent an additional layer (passive layer 5). The organic polymer layer and additional

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layer inherently have all of the memory-state transition properties of the claims because the structure and materials are the same as those of the claimed invention.

In re claim 14, Krieger discloses [0019] that in the first memory state, the organic polymer exhibits a first electrical resistivity, in the second memory state, the organic polymer exhibits a second electrical resistivity higher than the first, and the element is inherently a fuse type memory element.

In re claim 15, Krieger discloses [0019] that the memory-state transition is initiated by applying to the memory element state-transition facilitating agents such as electrical voltage.

In re claims 16-25, Krieger shows [fig. 5] that the organic polymer layer is adjacent an additional layer (passive layer 5). The organic polymer layer and additional layer inherently have all of the memory-state transition properties of the claims because the structure and materials are the same as those of the claimed invention.

In re claims 26 and 27, Krieger discloses that upon application of a switch, the memory element irreversibly transitions from the first memory state to the second memory state [0045] or reversibly transitions from the first memory state to a second memory state and back to the first memory state with a second switch [0050] since a switching means is inherently used to turn the voltage on or off.

In re claims 32, Krieger discloses [0002] that the invention pertains to a computer system comprising a processor and memory having a number of memory elements.

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The appellant's arguments against Chow are persuasive. Therefore, the rejection of claims 1-3, 14, 15, and 28-32 over Chow (US 6,649,903) is withdrawn.

#### (10) Response to Argument

The appellant primarily argues (1) that the Affidavit submitted on July 15, 2005 is sufficient to overcome the Stasiak reference. The appellant also argues (2) that Stasiak and Krieger do not show all of the elements of the claims. The examiner believes that the rejections are still proper and discloses all of the limitations of the claims.

(1) In re the arguments that the Rule 131 Affidavit submitted on July 15, 2005 properly shows conception and reduction to practice of the current invention prior to June 14, 2002 (the filing date of the Stasiak Publication), the examiner still believes that such document is not sufficient to overcome Stasiak. The appellants assert in the appeal brief only that "the exhibits show a variety of different data collected from experimental investigation of memory devices, or switches, fabricated from organic polymers and overlapping conductive materials." The applicant further adds that the Exhibit 1 shows families of voltage curves, that Exhibit 3 discusses a memory element comprising PTCDA sandwiched between a p-silicon substrate and gold contact, that Exhibit 4 shows the illustration of changes observed in a cathode of a memory element, and that Exhibit 8 shows another example of a diagram of a memory element. However, the examiner cannot ascertain these asserted descriptions due to the fact that none of the figures, drawings and graphs are properly labeled with the term "Exhibit 1, 2, 3, etc."

There is no explanation of the figures, drawings, and graphs in the affidavit so one of ordinary skill in the art would not be able to determine what the invention is. For instance, the first page of the exhibits, labeled with a 1 and a circle around it (assumed to be Exhibit 1) shows a graph with the title 150 nm PTCDA. The Y and X axis are labeled current and voltage respectively. The appellant claims that Exhibit 1 shows a current/voltage curve obtained by measuring the current through memory-element embodiments of the PTCDA organic layer sandwiched between aluminum and silver electrodes. However, the legend of Exhibit 1 recites "Al//Si (n+ip+)//PTCDA 1500 Å)." It seems that Aluminum (Al) and Silicon (Si) [not Silver (Ag)] are somehow a part of this graph, but it cannot be determined if the PTCDA layer is formed between electrodes. The legend could be interpreted as meaning that the PTCDA layer is doped with aluminum and silicon. On page 6 of the Exhibits, labeled 3 with a circle around it (assumed to be Exhibit 3), the description only states that a PTCDA layer is formed on a p doped silicon (p-Si) with an gold (Au) top contact. The Exhibit is entitled "Shelf-test (PTCDA)." The Exhibit does not specifically mention that a memory device is formed using the PTCDA layer. The exhibit only mentions the results of testing the PTCDA layer on an electrode. The pages pertaining to what is assumed to be Exhibit 4 (page with 4 and a circle around it) disclose stressing an organic material. The first page of what is assumed to be Exhibit 8 ("Overview: Conductivity of PEDT:PSS films") do in fact show a diagram of a PEDT/PSS layer sandwiched between an Au and ITO layer as the appellant argues. However, the disclosure of that exhibit only describes preparation and testing of the device. Just because one generates current/voltage curves for a device

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does not specifically mean that a memory device has been formed. It may simply mean that one is testing the properties of a material/device. In this case, the current/voltage curves of the appellant's affidavit appear to only show the properties of the inventive organic polymer layer, said voltages applied via aluminum and silicon electrodes. There is nothing in that disclosure that would lead one of ordinary skill in the art to determine that the device is a memory element.

In essence, at best the examiner can only determine that the appellant invented an polymer layer (in this case the PTCDA layer). There is no evidence of conception of a memory device having the PTCDA polymer layer or the reduction to practice of a memory device having the PTCDA polymer layer. The instant invention pertains to an organic-polymer-based memory element comprising: at least two overlapping conductive signal lines; and at least on organic polymer layer within the region of overlap between the two signal lines. As stated in the previous rejections since the filing of the Rule 131 Affidavit, there is nothing in the evidence that suggests the reduction to practice of an organic-polymer based memory element. The Responses to the Affidavit have clearly recited the examiner's reasons for the rejection. Therefore, the rejection of the Affidavit is proper and Stasiak is a citable reference.

The rule requires that applicant make an oath to facts establishing the requisite conception plus reduction to practice before the date of the reference, conception plus diligence up to the reduction to practice, or conception plus diligence up to the filing of the application. Here, the affidavit is completely devoid of facts from which these conclusions can be derived. Regarding conception, the affidavit describes the rule,

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indicates that documents are attached, and says nothing more than "From these documents and/or models, it can be seen that the invention in this application was made at least by the date of Stasiak." As such, no specific facts are actually established from which a conclusion can be made that conception occurred. For diligence, there is a statement that a time line is attached, however, no timeline is presented nor activities described, so absolutely no facts are established from which a determination can be made that appellant was diligent.

Further, in reviewing the drawings and attempting to guess what facts may be supportable by those drawings, no indication of memory states are found and no evidence is presented that the missing limitations are obvious, so the claimed invention is not met by the conception.

In re appellant's arguments on page 8-9 regarding the conception being shown because there are two resistance states, it is noted that the claims require "two overlapping conductive signals lines; and at least one organic polymer layer within the region of overlap between the two signal lines, the organic polymer layer having at least two detectable memory states, transitions between which arise from one of changes in chemical bonds and changes in organic polymer doping. There is no evidence of recognition of memory states, the lines being signal lines, or transitions between which arise from one of changes in chemical bonds and changes in organic polymer doping. In fact there are no statements in the affidavit at all about what is shown, so there is nothing we can do but guess at what the drawings represent. In fact, no specific drawing can be identified as having an associated date, as the drawings are

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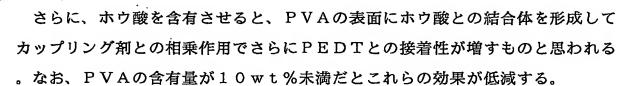
unlabeled. So, there is no way to tell which drawings if any correspond with any of the exhibits 1-8 because the affidavit has not asserted any correspondence.

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(2) In re the arguments that Stasiak and Krieger et al. do not show the "organic polymer layer having at least two detectable memory states, transitions between which arise from one of changes in chemical bonds and changes in organic polymer doping" the examiner believes that the references disclose the elements of the claims. For Stasiak, the appellant specifically asserts that the transitions between the at least two detectable memory states arise from changes in the accumulation of charge or polymer orientations but not changes in one of chemical bonds or organic-polymer doping. The examiner believes that Stasiak discloses the limitations in question. In [0023] of Stasiak specifically recites:

"Charge transport, in the form of hole or electron transport, may occur between adjacent donor or acceptor molecules, respectively. Such a process can be described as a one-electron <u>oxidation or reduction</u> process between neutral functional groups and their charged derivatives."

In essence, Stasiak discloses that molecules of the organic polymer layer accept or donate holes or electrons in an oxidation or reduction process. The exchange of electrons is known as a chemical reaction and a chemical reaction is known as a change in the chemical bonds of the molecules. As a teaching reference, permitted by the MPEP 1207.03 (III), Victor Gold ("Gold Book, Compendium of Chemical Terminology") is cited to define a change in chemical bond (or chemical reaction. Gold states on the first page in the first paragraph that:



[0030]

#### 【実施例】

続いて、以下のようにして製造した実施例及び従来例に基づいて本発明をさら に詳細に説明する。

#### (実施例1)

PET繊維を主体繊維とし、PVAをバインダーとして10wt%以上含有するセパレータを用い、以下のようにして固体電解コンデンサを作成した。表面に酸化皮膜層が形成された陽極箔と陰極箔に電極引き出し手段を接続し、両電極箔を上記のセパレータを介して巻回してコンデンサ素子を形成した。そして、このコンデンサ素子をリン酸二水素アンモニウム水溶液に40分間浸漬して修復化成を行った。修復化成後、このコンデンサ素子を100で乾燥した後、5wt%ホウ酸水溶液に常温で数分間浸漬し、150で1時間乾燥をおこなった。また、 $1wt\%N-\beta$ (アミノエチル) $\gamma-$ アミノプロピルメトキシシラン水溶液に常温で1分間浸漬し、80で1時間乾燥を行った。

一方、所定の容器に、EDTと45%のパラトルエンスルホン酸第二鉄のエタノール溶液を混合し、コンデンサ素子を上記混合液に10秒間浸漬し、120℃、60分加熱して、コンデンサ素子内でPEDTの重合反応を発生させ、固体電解質層を形成した。そして、このコンデンサ素子を有底筒状の外装ケースに挿入し、開口端部に封口ゴムを装着して、加締め加工によって封止した。その後に、150℃、120分、5.2Vの電圧印加によってエージングを行い、固体電解コンデンサを形成した。なお、この固体電解コンデンサの定格電圧は2.5WV、定格容量は180μ Fである。

[0031]

#### (実施例2)

ホウ酸水溶液に浸漬せず、その他の条件及び工程は、実施例1と同様である。 (比較例)



ホウ酸水溶液にも、カップリング剤にも浸漬せず、その他の条件及び工程は、 実施例1と同様である。

[0032]

#### [比較結果]

上記の方法により得られた実施例 1、実施例 2 及び比較例について、初期特性 を調べたところ表 1 に示したような結果が得られた。

#### 【表1】

	ホウ酸浸漬	シランカップリング 剤浸漬	初期特性	
			Cap (μF)	ESR (Ω ∕ 100kHz)
実施例1	あり	あり	152	0. 021
実施例2	なし	あり	143	0. 021
比較例	なし	なし	132	0. 023

[0033]

表1から明らかなように、共にホウ酸に浸漬することなく、カップリング剤に 浸漬するか否かが異なる実施例2と比較例についてみると、カップリング剤を含 有させた実施例2は、比較例に比べて静電容量は約1.08倍に増大し、ESR は約91%に低減した。さらに、ホウ酸を含有させた実施例1は、実施例2に比 べてさらに静電容量が増大した。

また、PVAをバインダーとして含まないセパレータを用いた場合と比較した ところ、ショート電圧は20V上昇した。

[0034]

#### 【発明の効果】

以上述べたように、本発明によれば、セパレータとして、ビニル基を有する化

合物をバインダーとして10wt%以上含むセパレータを用い、重合性モノマーと酸化剤を含浸する前に、所定のカップリング剤をコンデンサ素子内に含有させることにより、ESRの低減と、静電容量の向上及び耐電圧の向上を図ることが

できる固体電解コンデンサの製造方法を提供することができる。



【書類名】 要約書

#### 【要約】

【課題】 ESRの低減と、静電容量の向上及び耐電圧の向上を図ることができる固体電解コンデンサの製造方法を提供する。

【解決手段】 表面に酸化皮膜層が形成された陽極箔と陰極箔を、ビニル基を有する化合物をバインダーとして10wt%以上含むセパレータを介して巻回してコンデンサ素子を形成し、このコンデンサ素子に修復化成を施す。そして、所定のカップリング剤を含有させた後、このコンデンサ素子を重合性モノマーと酸化剤の混合液に浸漬し、コンデンサ素子内で導電性ポリマーの重合反応を発生させ、固体電解質層を形成する。そして、このコンデンサ素子を外装ケースに挿入し、開口端部に封口ゴムを装着して、加締め加工によって封止した後、エージングを行い、固体電解コンデンサを形成する。



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